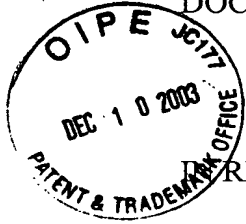


DOCKET NO: 219030US2S



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

RE APPLICATION OF :

Toshitake YAEGASHI

: EXAMINER: PIZARRO CRESPO, M.

SERIAL NO: 10/058,343 :

FILED: JANUARY 30, 2002

: GROUP ART UNIT: 2814

FOR: NON-VOLATILE  
SEMICONDUCTOR MEMORY DEVICE  
AND METHOD OF MANUFACTURING  
THE SAME :

AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated September 10, 2003, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.

**Remarks** begin on page 23 of this paper.

12/11/2003 JADD01 00000011 10058343

01 FC:1201 344.00 DP  
02 FC:1202 162.00 DP

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